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CAT522

Configured Digitally Programmable Potentiometer (DPP™): **Programmable Voltage Applications**

FEATURES

- Two 8-bit DPPs configured as programmable voltage sources in DAC-like applications
- Independent reference inputs
- Non-volatile NVRAM memory wiper storage
- Output voltage range includes both supply rails
- 2 independently addressable buffered output wipers
- 1 LSB accuracy, high resolution
- Serial Microwire-like interface
- Single supply operation: 2.7V 5.5V
- Setting read-back without effecting outputs

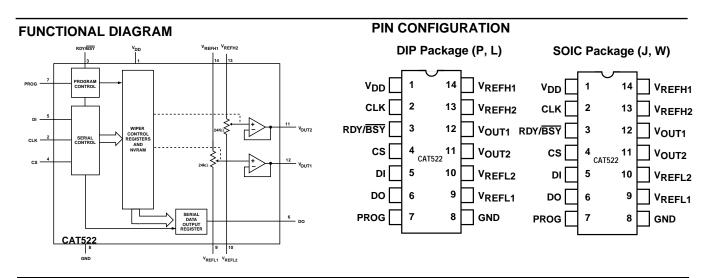
DESCRIPTION

The CAT522 is a dual, 8-bit digitally-programmable potentiometer (DPP™) configured for programmable voltage and DAC-like applications. Intended for final calibration of products such as camcorders, fax machines and cellular telephones on automated high volume production lines, it is also well suited for self-calibrating systems and for applications where equipment which requires periodic adjustment is either difficult to access or in a hazardous environment.

The CAT522 offers two independently programmable DPPs each having its own reference inputs and each capable of rail to rail output swing. The wipers are buffered by rail to rail opamps. Wiper settings, stored in non-volatile NVRAM memory, are not lost when the device is powered down and are automatically reinstated when power is returned. Each wiper can be dithered to test new output values without effecting the stored settings and stored settings can be read back without disturbing the DPP's output.

The CAT522 is controlled with a simple 3-wire, microwirelike serial interface. A Chip Select pin allows several devices to share a common serial interface. Communication back to the host controller is via a single serial data line thanks to the CAT522 Tri-Stated Data Output pin. A RDY/BSY output working in concert with an internal low voltage detector signals proper operation of the non-volatile NVRAM memory Erase/Write cycle.

The CAT522 is available in the 0°C to 70°C commercial and -40°C to 85°C industrial operating temperature ranges. Both 14-pin plastic DIP and surface mount packages are available.



OGENX

Automated product calibration.

APPLICATIONS

- Remote control adjustment of equipment
- Offset, gain and zero adjustments in selfcalibrating and adaptive control systems.
- Tamper-proof calibrations.
- DAC (with memory) substitute.





ABSOLUTE MAXIMUM RATINGS

Supply Voltage*
V_{DD} to GND0.5V to +7V
Inputs
CLK to GND0.5V to V _{DD} +0.5V
CS to GND0.5V to V _{DD} +0.5V
DI to GND0.5V to V_{DD} +0.5V
RDY/BSY to GND0.5V to V _{DD} +0.5V
PROG to GND0.5V to V _{DD} +0.5V
$V_{REF}H$ to GND0.5V to V_{DD} +0.5V
$V_{REF}L$ to GND0.5V to V_{DD} +0.5V
Outputs
D_0 to GND0.5V to V_{DD} +0.5V
V_{OUT} 1– 4 to GND0.5V to V_{DD} +0.5V

Operating Ambient Temperature

Commercial ('C' or Blank suffix) .	0°C to +70°C
Industrial ('I' suffix)	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature	-65°C to +150°C
Lead Soldering (10 sec max)	+300°C

* Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Absolute Maximum Ratings are limited values applied individually while other parameters are within specified operating conditions, and functional operation at any of these conditions is NOT implied. Device performance and reliability may be impaired by exposure to absolute rating conditions for extended periods of time.

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Min	Max	Units	Test Method
V _{ZAP} ⁽¹⁾	ESD Susceptibility	2000		Volts	MIL-STD-883, Test Method 3015
I _{LTH} ⁽¹⁾⁽²⁾	Latch-Up	100		mA	JEDEC Standard 17

NOTES: 1. This parameter is tested initially and after a design or process change that affects the parameter.

2. Latch-up protection is provided for stresses up to 100mA on address and data pins from -1V to V_{CC} + 1V.

POWER SUPPLY

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{DD1}	Supply Current (Read)	Normal Operating	_	400	600	μA
I _{DD2}	Supply Current (Write)	Programming, $V_{DD} = 5V$	_	1600	2500	μA
		$V_{DD} = 3V$	_	1000	1600	μA
V _{DD}	Operating Voltage Range		2.7	_	5.5	V

LOGIC INPUTS

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
IIH	Input Leakage Current	$V_{IN} = V_{DD}$	_		10	μΑ
IIL	Input Leakage Current	$V_{IN} = 0V$		—	-10	μΑ
VIH	High Level Input Voltage		2		V_{DD}	V
VIL	Low Level Input Voltage		0	_	0.8	V

LOGIC OUTPUTS

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{OH}	High Level Output Voltage	I _{OH} = -40μA	V _{DD} -0.3	_	_	V
VIL	Low Level Output Voltage	I_{OL} = 1 mA, V_{DD} = +5V			0.4	V
		$I_{OL} = 0.4 \text{ mA}, V_{DD} = +3V$			0.4	V

POTENTIOMETER CHARACTERISTICS

 V_{DD} = +2.7V to +5.5V, $V_{REF}H$ = V_{DD} , $V_{REF}L$ = 0V, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
R _{POT}	Potentiometer Resistance			24		kΩ
	R _{POT} to R _{POT} Match		—	<u>+</u> 0.5	<u>+</u> 1	%
	Pot Resistance Tolerance				<u>+</u> 20	%
	Voltage on V _{REFH} pin		2.7		V _{DD}	V
	Voltage on V _{REFL} pin		0V		V _{DD} - 2.7	V
	Resolution			0.4		%
INL	Integral Linearity Error			0.5	1	LSB
DNL	Differential Linearity Error			0.25	0.5	LSB
R _{OUT}	Buffer Output Resistance				10	Ω
I _{OUT}	Buffer Output Current				3	mA
TC _{RPOT}	TC of Pot Resistance			300		ppm/°C
C _H /C _L	Potentiometer Capacitances			8/8		pF

AC ELECTRICAL CHARACTERISTICS:

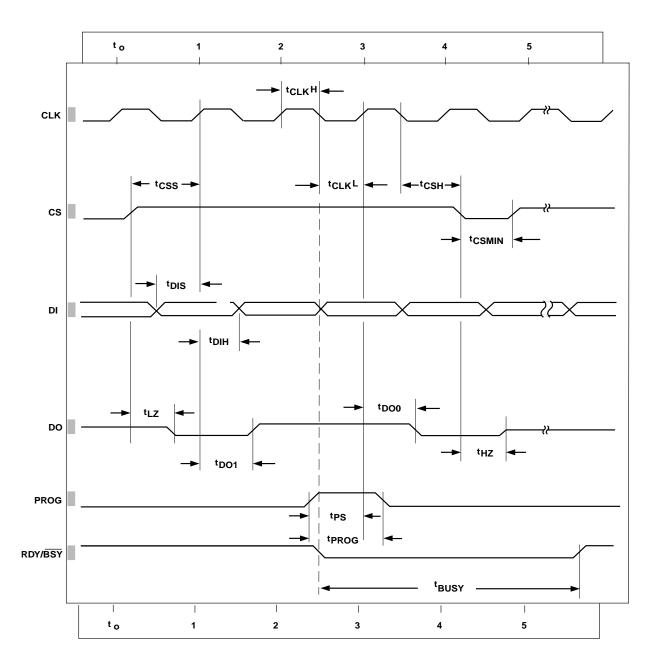
 V_{DD} = +2.7V to +5.5V, $V_{REF}H$ = V_{DD} , $V_{REF}L$ = 0V, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Digital						
t _{CSMIN}	Minimum CS Low Time		150			ns
t _{CSS}	CS Setup Time		100			ns
t _{CSH}	CS Hold Time		0			ns
t _{DIS}	DI Setup Time	CL=100pF,	50	_		ns
t _{DIH}	DI Hold Time	see note 1	50	—	_	ns
t _{DO1}	Output Delay to 1		_		150	ns
t _{DO0}	Output Delay to 0			_	150	ns
t _{HZ}	Output Delay to High-Z		_	400		ns
t _{LZ}	Output Delay to Low-Z			400		ns
t _{BUSY}	Erase/Write Cycle Time			4	5	ms
t _{PS}	PROG Setup Time		150			ns
t _{PROG}	Minimum Pulse Width		700	_		ns
t _{CLK} H	Minimum CLK High Time		500			ns
t _{CLK} L	Minimum CLK Low Time		300			ns
f _C	Clock Frequency		DC	—	1	MHz
Analog						
t _{DS}	DPP Settling Time to 1 LSB	$C_{LOAD} = 10 \text{ pF}, V_{DD} = +5 \text{V}$	_	3	10	μs
		$C_{LOAD} = 10 \text{ pF}, V_{DD} = +3V$		6	10	μs

NOTES: 1. All timing measurements are defined at the point of signal crossing V_{DD} / 2.

2. These parameters are periodically sampled and are not 100% tested.

A. C. TIMING DIAGRAM



PIN DESCRIPTION

Pin	Name	Function
1	V _{DD}	Power supply positive
2	CLK	Clock input pin
3	RDY/BSY	Ready/Busy output
4	CS	Chip select
5	DI	Serial data input pin
6	DO	Serial data output pin
7	PROG	EEPROM Programming Enable
		Input
8	GND	Power supply ground
9	V _{REFL1}	Minimum DPP 1 output voltage
10	V _{REFL2}	Minimum DPP 2 output voltage
11	V _{OUT2}	DPP 2 output
12	V _{OUT1}	DPP 1 output
13	V _{REFH2}	Maximum DPP 2 output voltage
14	V _{REFH1}	Maximum DPP 1 output voltage

DPP addressing is as follows:

DPP OUTPUT	A0	A1
VOUT1	0	1
V _{OUT2}	1	1

DEVICE OPERATION

The CAT522 is a dual 8-bit configured digitally programmable potentiometer (DPP) whose outputs can be programmed to any one of 256 individual voltage steps. Once programmed, these output settings are retained in non-volatile memory and will not be lost when power is removed from the chip. Upon power up the DPPs return to the settings stored in non-volatile memory. Each DPP can be written to and read from independently without effecting the output voltage during the read or write cycle. Each output setting, which is useful for testing new output settings before storing them in memory.

DIGITAL INTERFACE

The CAT522 employs a 3 wire serial, Microwire-like control interface consisting of Clock (CLK), Chip Select (CS) and Data In (DI) inputs. For all operations, address and data are shifted in LSB first. In addition, all digital data must be preceded by a logic "1" as a start bit. The DPP address and data are clocked into the DI pin on the clock's rising edge. When sending multiple blocks of information a minimum of two clock cycles is required between the last block sent and the next start bit.

Multiple devices may share a common input data line by selectively activating the CS control of the desired IC. Data Outputs (DO) can also share a common line because the DO pin is Tri-Stated and returns to a high impedance when not in use.

CHIP SELECT

Chip Select (CS) enables and disables the CAT522's read and write operations. When CS is high data may be read to or from the chip, and the Data Output (DO) pin is active. Data loaded into the DPP control registers will remain in effect until CS goes low. Bringing CS to a logic low returns all DPP outputs to the settings stored in non-volatile memory and switches DO to its high impedance Tri-State mode.

Because CS functions like a reset the CS pin has been desensitized with a 30 ns to 90 ns filter circuit to prevent noise spikes from causing unwanted resets and the loss of volatile data.

CLOCK

The CAT522's clock controls both data flow in and out of the IC and non-volatile memory cell programming. Serial data is shifted into the DI pin and out of the DO pin on the clock's rising edge. While it is not necessary for the clock to be running between data transfers, the clock must be operating in order to write to non-volatile memory, even though the data being saved may already be resident in the DPP wiper control register.

No clock is necessary upon system power-up. The CAT522's internal power-on reset circuitry loads data from non-volatile memory to the DPPs without using the external clock.

As data transfers are edge triggered clean clock transitions are necessary to avoid falsely clocking data into the control registers. Standard CMOS and TTL logic families work well in this regard and it is recommended that any mechanical switches used for breadboarding or device evaluation purposes be debounced by a flip-flop or other suitable debouncing circuit.

VREF

 V_{REF} , the voltage applied between pins $V_{REFL} \& V_{REFL}$, sets the configured DPP's Zero to Full Scale output range where $V_{REFL} = Zero$ and $V_{REFH} = Full Scale$. V_{REF} can span the full power supply range or just a fraction of it. In typical applications $V_{REFH} \& V_{REFL}$ are connected across the power supply rails. When using less than the full supply voltage be mindful of the limits placed on V_{REFL} and V_{REFL} as specified in the References section of DC Electrical Characteristics.

READY/BUSY

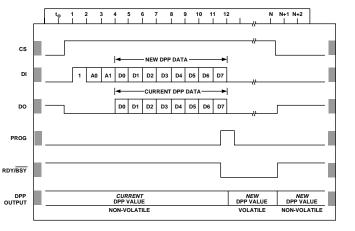
When saving data to non-volatile memory, the Ready/ Busy ouput (RDY/BSY) signals the start and duration of the non-volatile erase/write cycle. Upon receiving a command to store data (PROG goes high) RDY/BSY goes low and remains low until the programming cycle is complete. During this time the CAT522 will ignore any data appearing at DI and no data will be output on DO.

RDY/BSY is internally ANDed with a low voltage detector circuit monitoring V_{DD}. If V_{DD} is below the minimum value required for non-volatile programming, RDY/BSY will remain high following the program command indicating a failure to record the desired data in non-volatile memory.

DATA OUTPUT

Data is output serially by the CAT522, LSB first, via the Data Out (DO) pin following the reception of a start bit and two address bits by the Data Input (DI). DO becomes active whenever CS goes high and resumes its high impedance Tri-State mode when CS returns low. Tri-Stating the DO pin allows several 522s to share a





Doc. No. 2004, Rev. E

single serial data line and simplifies interfacing multiple 522s to a microprocessor.

WRITING TO MEMORY

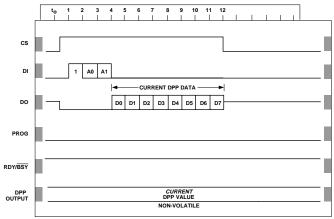
Programming the CAT522's non-volatile memory is accomplished through the control signals: Chip Select (CS) and Program (PROG). With CS high, a start bit followed by a two bit DPP address and eight data bits are clocked into the DPP wiper control register via the DI pin. Data enters on the clock's rising edge. The DPP output changes to its new setting on the clock cycle following D7, the last data bit.

Programming is accomplished by bringing PROG high sometime after the start bit and at least 150 ns prior to the rising edge of the clock cycle immediately following the D7 bit. Two clock cycles after the D7 bit the DPP wiper control register will be ready to receive the next set of address and data bits. The clock must be kept running throughout the programming cycle. Internal control circuitry takes care of generating and ramping up the programming voltage for data transfer to the non-volatile cells. The CAT522's non-volatile memory cells will endure over 1,000,000 write cycles and will retain data for a minimum of 100 years without being refreshed.

READING DATA

Each time data is transferred into a DPP control register currently held data is shifted out via the D0 pin, thus in every data transaction a read cycle occurs. Note, however, that the reading process is destructive. Data must be removed from the register in order to be read. Figure 2 depicts a Read Only cycle in which no change occurs in the DPP's output. This feature allows μ Ps to poll DPPs for their current setting without disturbing the output voltage but it assumes that the setting being read is also stored in non-volatile memory so that it can be restored at the end of the read cycle. In Figure 2 CS returns low before the 13th clock cycle completes. In doing so the non-volatile memory setting is reloaded into the DPP wiper control register. Since this value is the

Figure 2. Reading from Memory



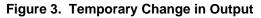
same as that which had been there previously no change in the DPP's output is noticed. Had the value held in the control register been different from that stored in nonvolatile memory then *a change would occur* at the read cycle's conclusion.

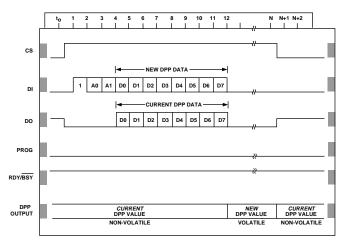
TEMPORARILY CHANGE OUTPUT

The CAT522 allows temporary changes in DPP's output to be made without disturbing the settings retained in non-volatile memory. This feature is particularly useful when testing for a new output setting and allows for user adjustment of preset or default values without losing the original factory settings.

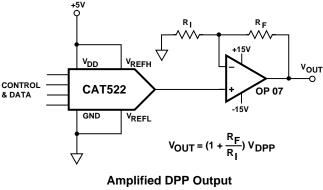
Figure 3 shows the control and data signals needed to effect a temporary output change. DPP wiper settings may be changed as many times as required and can be made to any of the two DPPs in any order or sequence. The temporary setting(s) remain in effect long as CS remains high. When CS returns low all two DPPs will return to the output values stored in non-volatile memory.

When it is desired to save a new setting acquired using this feature, the new value must be reloaded into the DPP wiper control register prior to programming. This is because the CAT522's internal control circuitry discards from the programming register the new data two clock cycles after receiving it if no PROG signal is received.



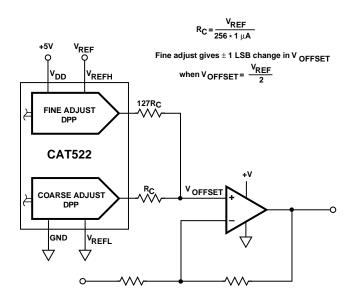


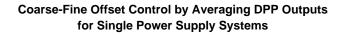
$V_{DD} = \frac{V_{i}}{225} (V_{FS} - V_{ZERO}) + V_{ZERO} + V_{ZERO} + V_{VEF} = 5V_{FS} + V_{ZERO} + V_{ZERO} + V_{VEF} = 5V_{FS} + V_{VEF} = 5V_{FS} + V_{FS} = 0.99 V_{REF} + V_{REF} = 5V_{FS} + V_{RF} = 1111 + 1111 + \frac{255}{255} (.98 V_{REF}) + .01 V_{REF} = .990 V_{REF} + V_{OUT} = +4.90 + 1000 + 0000 + \frac{128}{255} (.98 V_{REF}) + .01 V_{REF} = .502 V_{REF} + V_{OUT} = +4.90 + 1111 + 1111 + \frac{127}{255} (.98 V_{REF}) + .01 V_{REF} = .502 V_{REF} + V_{OUT} = +0.00 + 1111 + 1111 + \frac{127}{255} (.98 V_{REF}) + .01 V_{REF} = .498 V_{REF} + V_{OUT} = -0.00 + 1111 + 1111 + \frac{127}{255} (.98 V_{REF}) + .01 V_{REF} = .498 V_{REF} + V_{OUT} = -0.00 + 1000$		ITS	DPP INPUT	DPP OUTPUT	ANALOG OUTPUT
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$ \begin{array}{c} \hline R_{i} \\ \hline For R_{i} = R_{F} \\ V_{OUT} = 2V_{DPP} - V_{i} \end{array} $ Bipolar DPP Output $ \begin{array}{c} 0000 & 0001 & \overline{255} (.98 V_{REF}) + .01 V_{REF} = .014 V_{REF} \\ 0000 & 0000 & \overline{0} \\ \overline{255} (.98 V_{REF}) + .01 V_{REF} = .010 V_{REF} \\ V_{OUT} = -4.90 \\ V_{OUT} = -4.90 \\ V_{OUT} = -4.90 \\ \hline V_{OUT} = -4.9$	GND V _{REFL}	-15V			V _{OUT} = +0.02V V _{OUT} = -0.02V
V _{OUT} = 2V _{DPP} -V _i Bipolar DPP Output	\checkmark	R _i			V _{OUT} = -4.86V
+5V Q		$V_{OUT} = 2V_{DPP} - V_i$		$\frac{0}{255}$ (.98 V _{REF}) + .01 V _{REF} = .010 V _{REF}	V _{OUT} = -4.90V
		+5V	PP Output		

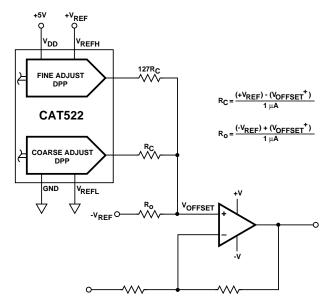


CONTRO

APPLICATION CIRCUITS (Cont.)

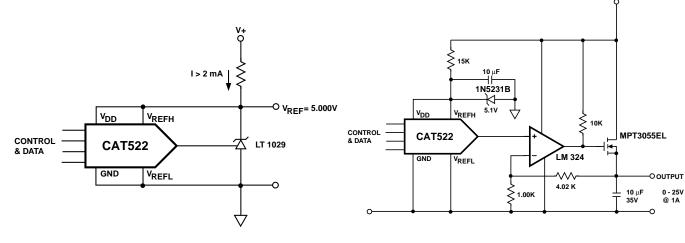






Coarse-Fine Offset Control by Averaging DPP Outputs for Dual Power Supply Systems

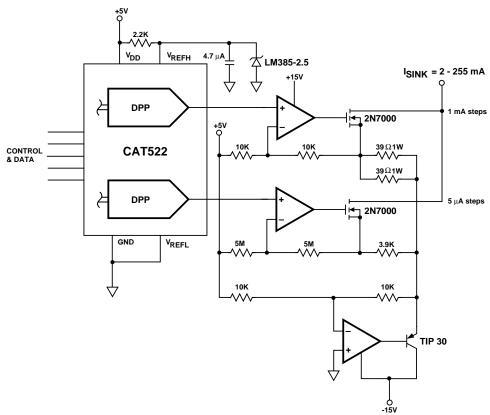
28 - 32V



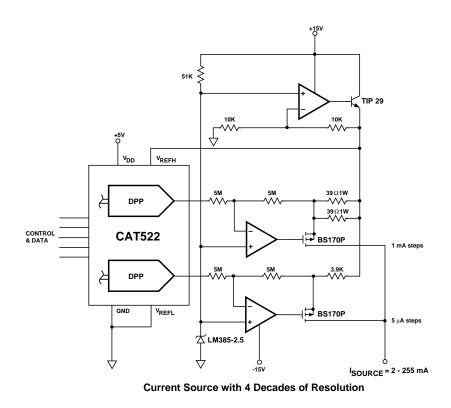
Digitally Trimmed Voltage Reference

Digitally Controlled Voltage Reference

APPLICATION CIRCUITS (Cont.)

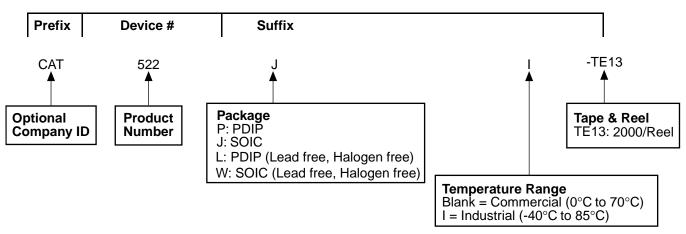


Current Sink with 4 Decades of Resolution



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ORDERING INFORMATION



Notes:

(1) The device used in the above example is a CAT522JI-TE13 (SOIC, Industrial Temperature, Tape & Reel)

REVISION HISTORY

Date	Rev.	Reason
3/16/2004	D	Updated Potentiometer Characteristics
7/12/2004	E	Updated Functional Diagram
		Updated Potentiometer Characteristics

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